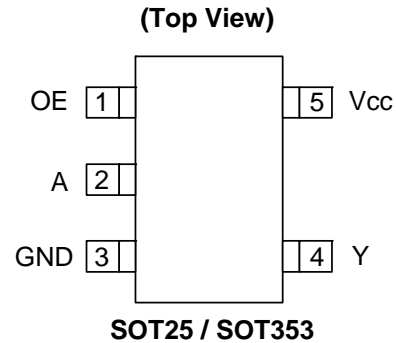


Description

The 74AHC1G126 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a LOW-level is applied to the output enable (OE) pin. The device is designed for operation with a power supply range of 2.0V to 5.5V.

Pin Assignments



Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- ESD Protection per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

Applications

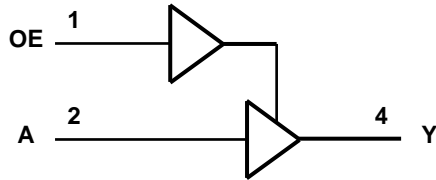
- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Personal Navigation / GPS
 - MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html.

Pin Descriptions

| Pin Name | Pin NO. | Description |
|-----------------|---------|----------------|
| OE | 1 | Output Enable |
| A | 2 | Data Input |
| GND | 3 | Ground |
| Y | 4 | Data Output |
| V _{CC} | 5 | Supply Voltage |

Logic Diagram



Function Table

| Inputs | | Output |
|--------|---|--------|
| OE | A | Y |
| H | H | H |
| H | L | L |
| L | X | Z |

Absolute Maximum Ratings (Note 2)

| Symbol | Description | Rating | Unit |
|-----------|--|------------------------|-------------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD CDM | Charged Device Model ESD Protection | 1 | KV |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V_{CC} | Supply Voltage Range | -0.5 to 6.5 | V |
| V_I | Input Voltage Range | -0.5 to 6.5 | V |
| V_O | Voltage applied to output in high or low state | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IK} | Input Clamp Current $V_I < 0$ | -20 | mA |
| I_{OK} | Output Clamp Current ($V_O < 0$ or $V_O > V_{CC}$) | ± 20 | mA |
| I_O | Continuous output current ($V_O = 0$ to V_{CC}) | ± 25 | mA |
| I_{CC} | Continuous current through V_{CC} | 50 | mA |
| I_{GND} | Continuous current through GND | -50 | mA |
| T_J | Operating Junction Temperature | -40 to 150 | $^{\circ}C$ |
| T_{STG} | Storage Temperature | -65 to 150 | $^{\circ}C$ |

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

| Symbol | Parameter | Min | Max | Unit |
|---------------------|------------------------------------|--------------------------|----------|-------------|
| V_{CC} | Operating Voltage | 2 | 5.5 | V |
| V_{IH} | High-level Input Voltage | $V_{CC} = 2V$ | 1.5 | V |
| | | $V_{CC} = 3V$ | 2.1 | |
| | | $V_{CC} = 5.5V$ | 3.85 | |
| V_{IL} | Low-level input voltage | $V_{CC} = 2V$ | 0.5 | V |
| | | $V_{CC} = 3V$ | 0.9 | |
| | | $V_{CC} = 5.5V$ | 1.65 | |
| V_I | Input Voltage | 0 | 5.5 | V |
| V_O | Output Voltage | 0 | V_{CC} | V |
| I_{OH} | High-level output current | $V_{CC} = 2V$ | -50 | μA |
| | | $V_{CC} = 3.3V \pm 0.3V$ | -4 | mA |
| | | $V_{CC} = 5V \pm 0.5V$ | -8 | |
| I_{OL} | Low-level output current | $V_{CC} = 2V$ | 50 | μA |
| | | $V_{CC} = 5V \pm 0.5V$ | 4 | mA |
| | | $V_{CC} = 3V$ | 8 | |
| $\Delta t/\Delta V$ | Input transition rise or fall rate | $V_{CC} = 3.3V \pm 0.3V$ | 100 | ns/V |
| | | $V_{CC} = 5V \pm 0.5V$ | 20 | |
| T_A | Operating free-air temperature | -40 | 125 | $^{\circ}C$ |

Notes: 3. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics

| Symbol | Parameter | Test Conditions | V _{CC} | 25°C | | | -40°C to 85°C | | -40°C to 125°C | | Unit |
|-----------------|--|--|-----------------|------|------|-------|---------------|------|----------------|------|------|
| | | | | Min | Typ. | Max | Min | Max | Min | Max | |
| V _{OH} | High Level Output Voltage | I _{OH} = -50μA | 2V | 1.9 | 2 | | 1.9 | | 1.9 | | V |
| | | | 3V | 2.9 | 3 | | 2.9 | | 2.9 | | |
| | | | 4.5V | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | I _{OH} = -4mA | 3V | 2.58 | | | 2.48 | | 2.40 | | |
| | | I _{OH} = -8mA | 4.5V | 3.94 | | | 3.8 | | 3.70 | | |
| V _{OL} | Low Level Output Voltage | I _{OL} = 50μA | 2V | | | 0.1 | | 0.1 | | 0.1 | V |
| | | | 3V | | | 0.1 | | 0.1 | | 0.1 | |
| | | | 4.5V | | | 0.1 | | 0.1 | | 0.1 | |
| | | I _{OL} = 4mA | 3V | | | 0.36 | | 0.44 | | 0.55 | |
| | | I _{OL} = 8mA | 4.5V | | | 0.36 | | 0.44 | | 0.55 | |
| I _I | Input Current | V _I = 5.5 V or GND | 0 to 5.5V | | | ± 0.1 | | ± 1 | | ± 2 | μA |
| I _{OZ} | Z State Leakage Current | V _O = 0 to 5.5 V | 5.5V | | | 0.25 | | 2.5 | | 10 | μA |
| I _{CC} | Supply Current | V _I = 5.5V or GND I _O = 0 | 5.5V | | | 1 | | 10 | | 40 | μA |
| C _I | Input Capacitance | V _I = V _{CC} – or GND | 5.5V | | 2.0 | 10 | | 10 | | 10 | pF |
| θ _{JA} | Thermal Resistance Junction-to-Ambient | SOT25 | (Note 4) | | 195 | | | | | | °C/W |
| | | SOT353 | | | 430 | | | | | | |
| θ _{JC} | Thermal Resistance Junction-to-Case | SOT25 | (Note 4) | | 58 | | | | | | °C/W |
| | | SOT353 | | | 155 | | | | | | |

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

Switching Characteristics

$V_{CC} = 3.3V \pm 0.3$ (see Figure 1)

| Parameter | From (Input) | TO (OUTPUT) | | 25°C | | | -40°C to 85°C | | -40°C to 125°C | | Unit |
|-----------|--------------|-------------|------------|------|------|------|---------------|------|----------------|------|------|
| | | | | Min | Typ. | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | $C_L=15pF$ | 0.6 | 4.4 | 8.0 | 0.6 | 9.5 | 0.6 | 10.0 | ns |
| | | | $C_L=50pF$ | 0.6 | 6.3 | 11.5 | 0.6 | 13.0 | 0.6 | 14.5 | ns |
| t_{en} | OE | Y | $C_L=15pF$ | 0.6 | 4.9 | 8.0 | 0.6 | 9.5 | 0.6 | 10.0 | ns |
| | | | $C_L=50pF$ | 0.6 | 7.0 | 11.5 | 0.6 | 13.0 | 0.6 | 14.5 | ns |
| t_{dis} | OE | Y | $C_L=15pF$ | 0.6 | 6.3 | 9.7 | 0.6 | 11.5 | 0.6 | 12.5 | ns |
| | | | $C_L=50pF$ | 0.6 | 9.0 | 13.2 | 0.6 | 15.0 | 0.6 | 16.5 | ns |

$V_{CC} = 5V \pm 0.5V$ (see Figure 1)

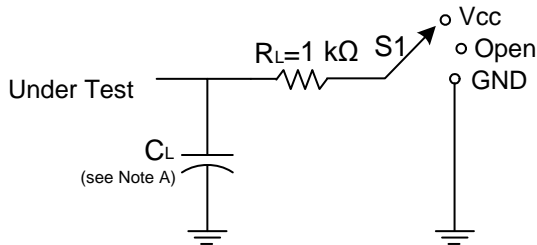
| Parameter | From (Input) | TO (OUTPUT) | | 25°C | | | -40 °C to 85 °C | | -40 °C to 125 °C | | Unit |
|-----------|--------------|-------------|------------|------|------|-----|-----------------|------|------------------|------|------|
| | | | | Min | Typ. | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | $C_L=15pF$ | 0.6 | 3.4 | 5.5 | 0.6 | 6.5 | 0.6 | 7.0 | ns |
| | | | $C_L=50pF$ | 0.6 | 4.7 | 7.5 | 0.6 | 8.5 | 0.6 | 9.5 | ns |
| t_{en} | OE | Y | $C_L=15pF$ | 0.6 | 3.6 | 5.6 | 0.6 | 6.3 | 0.6 | 7.0 | ns |
| | | | $C_L=50pF$ | 0.6 | 5.4 | 8.0 | 0.6 | 9.0 | 0.6 | 9.5 | ns |
| t_{dis} | OE | Y | $C_L=15pF$ | 0.6 | 4.3 | 6.8 | 0.6 | 8.0 | 0.6 | 8.5 | ns |
| | | | $C_L=50pF$ | 0.6 | 6.1 | 8.8 | 0.6 | 10.0 | 0.6 | 11.0 | ns |

Operating Characteristics

$T_A = 25\text{ }^\circ\text{C}$

| Parameter | | Test Conditions | $V_{CC} = 5V$ | | Unit |
|-----------|-------------------------------|----------------------|---------------|--|------|
| | | | Typ. | | |
| C_{pd} | Power dissipation capacitance | f = 1 MHz No Load | 12 | | pF |

Parameter Measurement Information



| TEST | S1 |
|-------------------|-------|
| t_{PLH}/t_{PHL} | Open |
| t_{PLZ}/t_{PZL} | Vload |
| t_{PHZ}/t_{PZH} | GND |

| V_{CC} | Inputs | | V_M | C_L | V_{Δ} |
|-----------------|----------|------------|------------|-------|--------------|
| | V_I | t_r/t_f | | | |
| $3.3V \pm 0.3V$ | V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF | 0.3V |
| $5V \pm 0.5V$ | V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 15pF | 0.3V |
| $3.3V \pm 0.3V$ | V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF | 0.3V |
| $5V \pm 0.5V$ | V_{CC} | $\leq 3ns$ | $V_{CC}/2$ | 50pF | 0.3V |

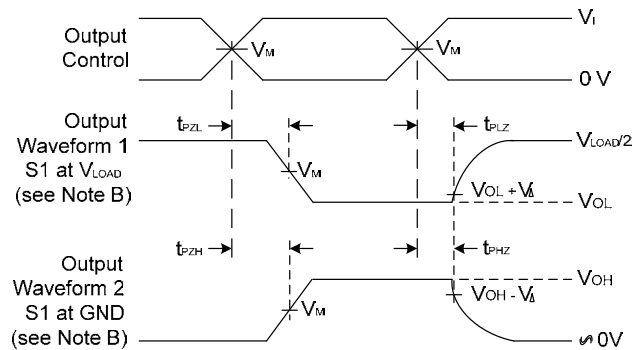
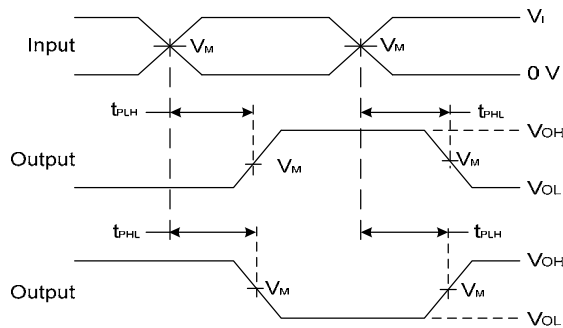
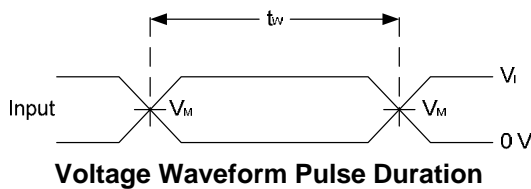
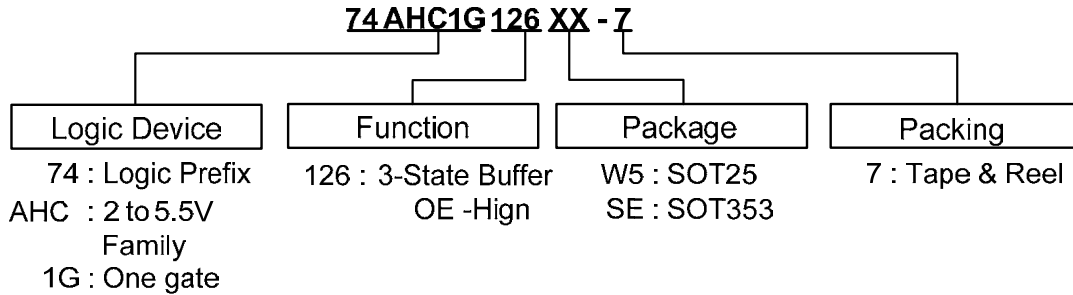


Figure 1. Load Circuit and Voltage Waveforms

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - E. t_{PZL} and t_{PZH} are the same as t_{EN} .
 - F. t_{PLH} and t_{PHL} are the same as t_{PD} .

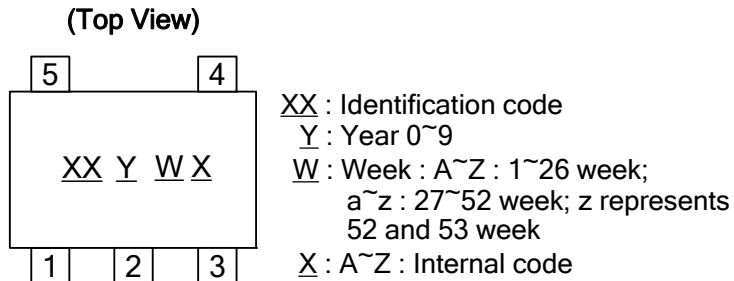
Ordering Information



| Device | Package Code | Packaging (Note 5) | 7" Tape and Reel | |
|----------------|--------------|--------------------|------------------|--------------------|
| | | | Quantity | Part Number Suffix |
| 74AHC1G126W5-7 | W5 | SOT25 | 3000/Tape & Reel | -7 |
| 74AHC1G126SE-7 | SE | SOT353 | 3000/Tape & Reel | -7 |

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

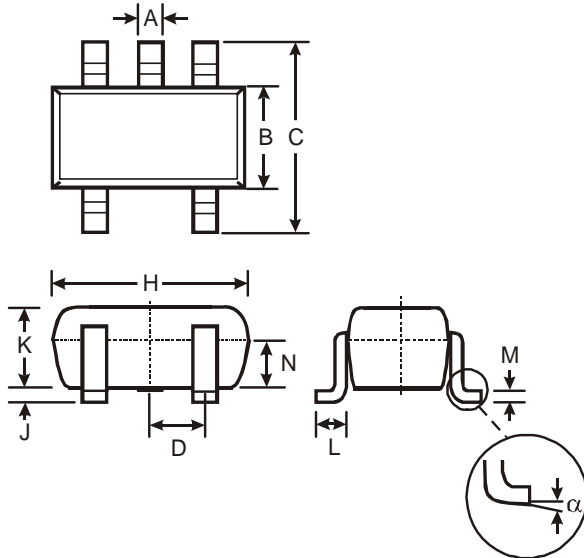
Marking Information



| Part Number | Package | Identification Code |
|--------------|---------|---------------------|
| 74AHC1G126W5 | SOT25 | YZ |
| 74AHC1G126SE | SOT353 | YZ |

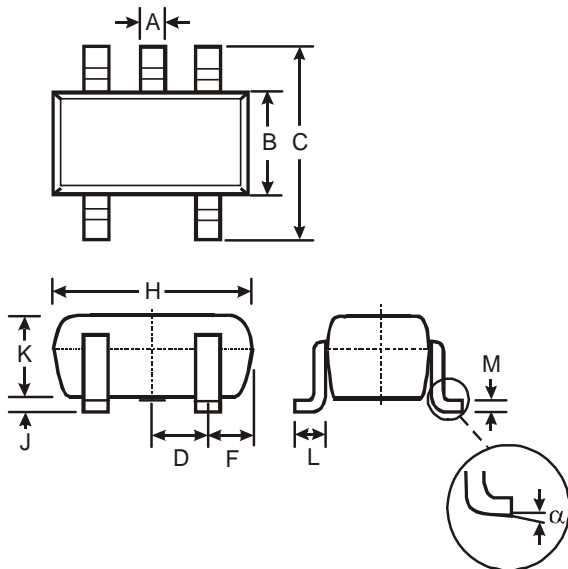
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



| SOT25 | | | |
|----------------------|-------|------|------|
| Dim | Min | Max | Typ |
| A | 0.35 | 0.50 | 0.38 |
| B | 1.50 | 1.70 | 1.60 |
| C | 2.70 | 3.00 | 2.80 |
| D | — | — | 0.95 |
| H | 2.90 | 3.10 | 3.00 |
| J | 0.013 | 0.10 | 0.05 |
| K | 1.00 | 1.30 | 1.10 |
| L | 0.35 | 0.55 | 0.40 |
| M | 0.10 | 0.20 | 0.15 |
| N | 0.70 | 0.80 | 0.75 |
| α | 0° | 8° | — |
| All Dimensions in mm | | | |

(2) Package Type: SOT353



| SOT353 | | |
|----------------------|----------|------|
| Dim | Min | Max |
| A | 0.10 | 0.30 |
| B | 1.15 | 1.35 |
| C | 2.00 | 2.20 |
| D | 0.65 Typ | |
| F | 0.40 | 0.45 |
| H | 1.80 | 2.20 |
| J | 0 | 0.10 |
| K | 0.90 | 1.00 |
| L | 0.25 | 0.40 |
| M | 0.10 | 0.22 |
| α | 0° | 8° |
| All Dimensions in mm | | |

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com

单击下面可查看定价，库存，交付和生命周期等信息

[>>Diodes Incorporated\(达达科技\(美台\)\)](#)